# Electrons diffraction scattering on a traveling wave – "Inelastic Kapitza-Dirac effect"

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In this paper conceptual points regarding electrons elastic (Kapitza-Dirac effect) and inelastic diffraction effect on the different type slowed electromagnetic wave structures/light gratings are considered. From the unified point of view it is analyzed the main works on this subject for last four decades in chronological order, pointing out the essential peculiarity inherent in induced Cherenkov, Compton, and undulator/wiggler processes too. This review article has also a goal to resolve confusion in scientific literature connected with the recently appeared paper [6] relating the electrons diffraction on a traveling wave in a dielectric medium.

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In recent years, especially after the realization of experiment on strongly coherent and intense laser beams [1], the interest to Kapitza–Dirac effect [2] has been increased. This, in particular, is conditioned by the significant role of observed electrons diffraction effect on high-intensity laser beams-gratings [3], [1], since the diffracted from highly coherent laser gratings electron beams are coherent with each other, and Kapitza–Dirac effect is a very convenient, perhaps the best means to realize coherent electron beams (see, also, the review paper [4]). This is important fact that can serve as a basis for construction of diverse type new tools, e.g., coherent beam splitters, new type electron interferometers which would operate at rather low electron energies etc. Furthermore, since 1975 the scope of the Kapitza–Dirac effect, which is valid for the electrons elastic scattering on a standing light wave/grating, has been extended [7], [8], [9] for inelastic diffraction scattering of electrons on a slowed travelling wave propagating with the phase velocity $\mathrm{v}_{ph} < c$ ($c$ is the light speed in vacuum), to consideration of general aspects of which is devoted the present review article. The motivation of the latter have two reasons. First -that is the most important, is connected with the essential peculiarity inherent in mentioned processes (induced Cherenkov, Compton, and undulator/wiggler) [7], [8], [9] -existence of a critical field, above which a nonlinear threshold phenomenon arises radically changing the dynamics of electron-slowed travelling wave interaction, and consequently, the situation for inelastic diffraction scattering. Second, electrons diffraction effect on a travelling wave in a dielectric medium requires a special consideration because of a confusion in scientific literature connected with the appearance recently of a paper on this subject [6]. Therefore, apart from the pure scientific interest, the current review has a goal to clear up the-state-of-the-art in the considering field for last four decades in chronological order, to avoid the further confusion and misunderstandings in scientific literature.

The predicted by Kapitza and Dirac in 1933 phenomenon of electrons diffraction scattering on a phase lattice of a standing light wave naturally for that time had an one-photon character because of the absence of strong and coherent radiation fields. The experimental situation has been reviewed by H. Schwarz in [26, 27] (see, also [25]). With the appearance of laser sources Kapitza-Dirac diffraction effect achieved multiphoton character, the probability of which in the field of strong counterpropagating laser beams has been done by F. Ehlotzky and C. Leubner in 1974 on the base of the Helmholtz–Kirchhoff diffraction theory [17, 18] (see, also [24] where a theoretical analysis is made of the scattering of electrons by a strong standing wave with a slowly varying amplitude). This is an elastic scattering of electrons moving in perpendicular direction to wavevectors of counterpropagating waves ($\mathbf{k}$ and $-\mathbf{k}$) of the same frequencies -to except the Doppler shifting because of longitudinal component of electrons' velocity, and a stationary periodic space-configuration (standing wave structure) is formed providing the phase matching between the electrons and counterpropagating waves, only at which the coherent scattering – electrons diffraction on a standing light-wave takes place.

Then, in 1975 this phenomenon has been developed by V.M. Haroutunian and H.K. Avetissian for bichromatic counterpropagating waves and electrons inelastic diffraction scattering on a slowed interference wave has been stated [7]. In this process, due to the induced Compton effect in the two wave fields an electron absorbs $s$ photons from the one wave (of frequency $\omega_1$) and coherently radiates $s$ photons into the other wave (of frequency $\omega_2$) and vice versa. This is the condition of coherency in the induced Compton process corresponding to the resonance between the Doppler-shifted frequencies in the intrinsic frame of reference of an electron in the bichromatic counterpropagating waves:

$$\omega_1\left(1-\frac{\mathrm{v}_x}{c}\right)=\omega_2\left(1+\frac{\mathrm{v}_x}{c}\right) \tag{1}$$

($\mathrm{v}_x$ is the electron longitudinal velocity with respect to counterpropagating waves), at which the conservation of the number of photons in the induced Compton process takes place, in contrast to spontaneous Compton effect in the strong wave field where after the multiphoton absorption a single photon is emitted. The result of such coherent scattering is equivalent to diffraction of electrons on a slowed interference wave in the form of a plane traveling wave:

$$E_1E_2\cos\left[(\omega_1-\omega_2)\left(t-\frac{\omega_1+\omega_2}{|\omega_1-\omega_2|}\frac{x}{c}\right)\right] \tag{2}$$

($E_{1,2}$ are the amplitudes of the waves' electric field strengths). So, because of nonstationary field Eq. (2) the energy of an electron does not conserved (in other words, the energies of absorbed and emitted photons are different) and in contradistinction to Kapitza–Dirac effect on a standing phase lattice here the scattering process is inelastic. The energy change $\Delta\mathcal{E}$ after the interaction is:

$$\Delta\mathcal{E} = s\hbar\left(\omega_1 - \omega_2\right),\ \Delta p_x = s\hbar\left(\omega_1 + \omega_2\right)/c,$$

$$\Delta p_y = 0;\ s = 0, \pm 1, \ldots. \tag{3}$$

(the waves, linearly polarized along the axis $y$, are propagating in the direction $x$ along which electron acquires momentum transfer $\Delta p_x$ in the interaction process; coordinate $z$ is cyclic, hence: $\Delta p_z \equiv 0$) which determines the maximums and minimums of diffraction peaks over the energy in the probability distribution of inelastic diffraction of electrons. For the latter, in accordance with Eq. (1), we shall direct the electron velocity v at the angle $\vartheta_c$ to the axis $x$ under the condition:

$$\mathrm{v}\cos\vartheta_c = c\frac{|\omega_1 - \omega_2|}{\omega_1 + \omega_2} \tag{4}$$

of coherency between two waves. At the condition Eq. (4) the traveling interference wave Eq. (2) in the intrinsic frame of reference moving with the electron (of velocity equal to phase velocity of the slowed wave $\mathrm{v}_{ph} = c\left|\omega_1 - \omega_2\right|/(\omega_1+\omega_2) < c$), the travelling wave becomes a standing phase lattice/light grating, and elastic diffraction scattering – Kapitza–Dirac effect occurs. It is obvious that in the laboratory frame of reference this is inelastic diffraction scattering.

However, the described picture of inelastic diffraction on the slowed traveling interference wave is only the kinematics of the electrons' coherent scattering in the induced Compton process with bichromatic counterpropagating waves. What concerns the dynamics of this interaction, as has been shown in the works [10], [11], and [15], the induced coherent processes such Cherenkov, Compton, and undulator/wiggler ones are possessed with basic peculiarity which radically changes the ordinary interaction dynamics of an electron with the periodic wave-field, and above a certain value of the wave intensity a nonlinear threshold phenomenon of electrons "reflection" or capture by a slowed traveling wave occurs. Hence, we must take into account this fact and only after the establishment of necessary dynamic condition for synchronous motion of an electron with the slowed wave one can speak about the inelastic diffraction effect on a traveling wave.

The exact investigation of the dynamics of induced Compton process reveals the existence of a critical field in this process

$$\xi_{cr}(\omega_1,\omega_2) \equiv \left(\xi_1 + \xi_2\right)_{cr} =$$

$$\frac{\mathcal{E}_0}{mc^2}\frac{\left|\omega_1\left(1 - \frac{\mathrm{v}}{c}\right) - \omega_2\left(1 + \frac{\mathrm{v}}{c}\right)\right|}{2\sqrt{\omega_1\omega_2}} \tag{5}$$

($\xi_{1,2} \equiv eE_{1,2}/mc\omega_{1,2}$ are the dimensionless relativistic invariant parameters of the waves' intensities, where $e$, $m$ are the charge and mass of the electron). Thus, if the intensity of a slowed interference wave Eq. (2) exceeds this critical value Eq. (5): $\xi_1 + \xi_2 > \xi_{cr}(\omega_1,\omega_2)$, a nonlinear threshold phenomenon of particle "reflection" or capture by the slowed traveling wave occurs [11], at which the periodic wave-field in the intrinsic frame of reference of the slowed interference wave becomes a potential barrier for a particle, instead of a standing phase lattice, and reflecting from this barrier electron abandons the wave. Therefore, the considering effect of electrons diffraction on a travelling wave propagating with the phase velocity $\mathrm{v}_{ph} < c$ can occur only if the total intensity of the waves is smaller than the critical value of corresponding induced process; in case of Compton one –Eq. (5): $\xi_1 + \xi_2 < \xi_{cr}(\omega_1,\omega_2)$.

It is necessary to note that the expression of Eq. (5) for critical field of induced Compton process corresponds to a case $\vartheta_c = 0$ when it has a simple form and exact analytic solution of this issue is succeeded. For inelastic diffraction effect that takes place at the angle $\vartheta_c$ satisfying to condition Eq. (4) of the induced Compton resonance, the formula of critical field has a relatively complex form and therefore it is not convenient to present here bulk expressions. The reader interested in more detailed information regarding the general cases of electrons "reflection" or capture by a slowed traveling wave at the arbitrary angle $\vartheta$ can find the corresponding expressions for critical field in the papers [14], [13], and [16], or more details in the work [12].

Electrons inelastic diffraction effect directly on a travelling wave has been developed in 1976 by H.K. Avetissian [8], proposing to use a dielectric medium for decreasing of the wave phase velocity -making it smaller $c$. It is clear that electron-travelling wave interaction at $\mathrm{v}_{ph} < c$ in a dielectric medium corresponds to induced Cherenkov process [8]. Thus, by the same physical consideration mentioned above, in [8] has been shown that if one direct the electron velocity v at the angle $\vartheta_{ch}$ to the wave propagation direction

$$\mathrm{v}\cos\vartheta_{ch} = \frac{c}{n}, \tag{6}$$

where $n$ is the refractive index of a dielectric medium, under this condition the travelling wave in the intrinsic frame of reference becomes a standing phase lattice on which diffraction scattering of electrons occurs. We will not repeat here the further consideration of inelastic diffraction effect in a dielectric medium, which has been done in many publications: [8], monographs [21], [23], and book [22]. Only let us to state here the restriction by the wave intensity effect for inelastic diffraction, representing the formula for critical field of induced Cherenkov process:

$$\xi_{cr}(\vartheta) = \frac{c}{2\mathrm{v}}\frac{\mathcal{E}}{mc^2}\frac{\left(1 - n\frac{\mathrm{v}}{c}\cos\vartheta\right)^2}{\left(n^2-1\right)\left|\sin\vartheta\right|};\qquad \vartheta \neq 0 \tag{7}$$

($\mathcal{E}$ is the electron initial energy) that confines the wave intensity for diffraction effect in a dielectric medium because of the nonlinear threshold phenomenon of particle "reflection" or capture by a traveling wave in a dielectric medium [10]. Consequently, for "Cherenkov diffraction" effect the wave intensity $\xi$ in a dielectric medium should be less than the critical value Eq. (7): $\xi < \xi_{cr}(\vartheta)$.

The third case of electrons inelastic diffraction scattering on a slowed traveling wave, developed by the H.K. Avetissian et al. in 1981 [9] again for vacuum case, is the propagation of a plane monochromatic wave through an electric and magnetic undulator/wiggler. In such space – time periodic structures, like to the considered above induced Compton process, a slowed interference wave is formed, on which diffraction scattering of electrons occurs by the described scheme, at the intensities below the corresponding critical values of nonlinear threshold phenomenon of electrons "reflection" or capture by a travelling wave in the electric and magnetic undulators (see [15]). As far as descriptions of electrons' inelastic diffraction scattering on a plane monochromatic wave in the electric and magnetic undulators are coincide in many features, here we will consider the more important case of magnetic undulator/wiggler, which is currently the most perspective coherent tool with extremely large length of coherency, specifically due to which the x-ray free electron laser has been realized in the wiggler.

At the propagation of a plane monochromatic wave of frequency $\omega$ and amplitude of electric field strength $E$ (let of linear polarization, with relativistic invariant parameter $\xi = eE/mc\omega$) in the linear undulator with the magnetic field

$$H_z(x) = H\cos\frac{2\pi}{l}x, \tag{8}$$

which is characterized by relativistic parameter

$$\xi_H = \frac{elH}{2\pi mc^2} \tag{9}$$

($l$ is the space period -undulator step), a slowed interference wave

$$\xi\xi_H\cos\omega\left(t - \frac{c}{1+\frac{\lambda}{l}}\frac{x}{c}\right) \tag{10}$$

is formed propagating with the phase velocity $\mathrm{v}_{ph} = c/(1+\frac{\lambda}{l}) < c$, where $\lambda = 2\pi c/\omega$ is the wavelength of monochromatic wave (the geometry is the same as in case of counterpropagating waves). Hence, if we direct the electron velocity v at the angle $\vartheta_u$ to the undulator axis (wave propagation direction):

$$\mathrm{v}\cos\vartheta_u = \frac{c}{1+\frac{\lambda}{l}}, \tag{11}$$

the slowed interference wave Eq. (10) in the intrinsic frame of reference will become a standing phase lattice on which inelastic diffraction scattering of electrons will occur. In accordance with the aforementioned dynamic statements for coherent processes, the inelastic diffraction will take place at the intensities of the total field $\xi + \xi_H$ below the corresponding critical intensity of this process: $\xi + \xi_H < \xi_{cr}\,(\lambda/l)$ [15]

$$\xi_{cr}\left(\frac{\lambda}{l}\right) \equiv (\xi+\xi_H)_{cr} = \frac{\left|1-\left(1+\frac{\lambda}{l}\right)\frac{\mathrm{v}}{c}\right|}{\sqrt{\frac{2\lambda}{l}\left(1+\frac{\lambda}{2l}\right)}}\frac{\mathcal{E}}{mc^2}. \tag{12}$$

Let us to note that Eq. (12) corresponds again to a case $\vartheta_u = 0$ for exact nonlinear solution, as was justified above for bichromatic counterpropagating waves.

It is important to note that the mentioned phenomenon of particle "reflection" in the induced coherent processes [10], [11], and [15] takes place even in the very weak wave-fields if the electrons initially are close to the resonance state, i.e. the electrons' initial longitudinal velocity $\mathrm{v}_x$ is close to the phase velocity $\mathrm{v}_{ph}$ of the slowed wave at which the critical field is very small too and the condition of $\xi < \xi_{cr}(\vartheta)$ may be violated [28], [12]. So, no matter how the traveling electromagnetic (EM) wave is weak, the described inelastic diffraction effect even on such a weak wave may not occur if the condition $\xi < \xi_{cr}(\vartheta)$ is not satisfied.

The considered effect of inelastic diffraction on a traveling wave in all three induced coherent processes has been described in the scope of relativistic quantum theory with the help of eikonal wave function – the solution of the Klein-Gordon equation for description of multiphoton processes at the electron-wave nonlinear interaction. As far as the method of solution of quantum equation of motion in eikonal approximation is general for described coherent processes, here we will represent only the dynamic results for inelastic diffraction in case of a traveling EM wave in a dielectric medium in the original form corresponding to the paper [8] and monographs [21], [23] or the book [22] for comparison its with the result of the paper [6] of 2015 pretended to priority for proposed effect of electrons diffraction on a traveling wave in a dielectric medium.

Thus, neglecting the spin interaction in the quadratic form of Dirac equation for an electron (as is known, at first, the spin interaction of an electron with a light-field is rather small compared with the charge interaction and, second, by it's nature is different than considering effect; regarding spin dynamics in the Kapitza-Dirac effect, see the paper [5]), the latter passes to the Klein-Gordon equation for electron in the field of a plane EM wave in a dielectric medium:

$$-\hbar^2\frac{\partial^2\Psi}{\partial t^2} = \left\{-\hbar^2c^2\bigtriangledown^2 + m^2c^4 + \right.$$

$$\left. 2ie\hbar c\mathbf{A}(\tau)\bigtriangledown + e^2A^2(\tau)\right\}\Psi. \tag{13}$$

($\hbar$ is the Planck constant, $\mathbf{A}(\tau)$ is the vector potential and $\tau \equiv t - n\frac{x}{c}$ -wave coordinate of a plane EM wave).

Equation (13) is solved in the eikonal approximation by electron wave function

$$\Psi\left(\mathbf{r},t\right)=\sqrt{\frac{N_0}{2\mathcal{E}}}f(x,t)\exp\left[\frac{i}{\hbar}\left(\mathbf{pr}-\mathcal{E}t\right)\right], \qquad (14)$$

according to which $f(x,t)$ is a slowly varying function with respect to free–electron wave function (the latter is normalized on $N_0$ particles per unit volume):

$$\left|\frac{\partial f}{\partial t}\right|<<\frac{\mathcal{E}}{\hbar}\left|f\right|; \qquad \left|\frac{\partial f}{\partial x}\right|<<\frac{p_x}{\hbar}\left|f\right|. \qquad (15)$$

Choosing a concrete polarization of the wave (assume a linear one along the axis $OY$) and taking into account Eq. (13) for $f(x,t)$ we will have a differential equation of the first order:

$$\frac{\partial f}{\partial t}+\mathrm{v}\cos\vartheta\frac{\partial f}{\partial x}=\frac{i}{2\hbar\mathcal{E}}\left[2ecp\sin\vartheta\cdot A_0(\tau)\cos\omega\tau\right.$$

$$\left.-e^2A_0^2(\tau)\cos^2\omega\tau\right]f(x,t), \qquad (16)$$

where $A_0(\tau)$ is a slowly varying amplitude of the vector potential of quasi-monochromatic wave and $\vartheta$ is the angle between the electron velocity and the wave propagation direction, as it noted above. Since should be $\xi_{\max}<\xi_{cr}<<1$ (to be below the ionization threshold of a dielectric medium too), then for actual values of parameters $p\sin\vartheta/mc>>\xi_{\max}$ and the last term $\sim A_0^2$ in Eq. (16) will be neglected. Changing to characteristic coordinates $\tau'=t-x/\mathrm{v}\cos\vartheta$ and $\eta'=t$, it will be obvious that at the fulfillment of the induced Cherenkov condition $\mathrm{v}\cos\vartheta_{ch}=c/n$ Eq. (6) the traveling wave in this frame of coordinates becomes a diffraction lattice over the coordinate $\tau'$ and for the scattered amplitude of the electron wave function from Eq. (16) we have

$$f(\tau')=\exp\left\{\frac{iecp\sin\vartheta_{ch}}{\hbar\mathcal{E}}\cos\omega\tau'\int_{\eta_1}^{\eta_2}A(\eta')d\eta'\right\}, \quad (17)$$

where $\eta_1$ and $\eta_2$ are the moments of the electron entrance into the wave and exit, respectively. If one returns to coordinates $x$ and $t$ and expands the exponential (17) into a series by Bessel functions for the total wave function (14) we will have

$$\Psi\left(\mathbf{r},t\right)=\sqrt{\frac{N_0}{2\mathcal{E}}}\exp\left(\frac{i}{\hbar}yp\sin\vartheta_{ch}\right)\sum_{s=-\infty}^{+\infty}i^sJ_s(\alpha)$$

$$\times\exp\left[\frac{i}{\hbar}\left(p\cos\vartheta_{ch}-\frac{sn\hbar\omega}{c}\right)x-\frac{i}{\hbar}\left(\mathcal{E}-s\hbar\omega\right)t\right], \quad (18)$$

where the argument of the Bessel function

$$\alpha=\frac{e\mathrm{v}\sin\vartheta_{ch}}{\hbar\omega}\int_{t_1}^{t_2}E(\eta')d\eta', \qquad (19)$$

and $E$ is the amplitude of the wave electric field strength. The wave function (18) describes inelastic diffraction scattering of the electrons on the slowed traveling wave in a dielectriclike medium. The electrons' energy and momentum after the scattering are

$$\mathcal{E}'=\mathcal{E}-s\hbar\omega, \quad p_x'=p\cos\vartheta_{ch}-\frac{sn\hbar\omega}{c},$$

$$p_y=\mathrm{const}; \quad s=0,\pm1,\ldots. \qquad (20)$$

The probability of this process

$$W_s=J_s^2\left[\frac{ec^2p\sin\vartheta_{ch}}{\hbar\omega\mathcal{E}}\int_{t_1}^{t_2}E(\eta')d\eta'\right]. \qquad (21)$$

The condition of the applied eikonal approximation (15) with Eq. (17) is equivalent to the conditions $\left|p_x'-p_x\right|<<p_x$ and $\left|\mathcal{E}'-\mathcal{E}\right|<<\mathcal{E}$, which with Eq. (20) gives: $|s|\,n\hbar\omega/c<<p$.

In the case of a monochromatic wave from Eq. (21) we have

$$W_s=J_s^2\left(\xi\frac{mc^2}{\hbar}\frac{cp\sin\vartheta_{ch}}{\mathcal{E}}t_0\right), \qquad (22)$$

where $t_0=t_2-t_1$ is the duration of the particle motion in the wave.

As is seen from Eq. (22) for the actual values of the parameters $\alpha>>1$, that is, the process is essentially multiphoton. The most probable number of absorbed/emitted Cherenkov photons is

$$\overline{s}\simeq\xi\frac{mc^2}{\hbar}\frac{\mathrm{v}}{c}\sin\vartheta_{ch}\cdot t_0. \qquad (23)$$

The energetic width of the main diffraction maximums $\Gamma(\overline{s})\simeq\overline{s}^{1/3}\hbar\omega_0$ and since $\overline{s}>>1$ then $\Gamma(\overline{s})<<\left|\mathcal{E}'-\mathcal{E}\right|$.

The scattering angles of the $s$-photon Cherenkov diffraction are determined by Eq. (20):

$$\tan\vartheta_s=\frac{sn\hbar\omega\sin\vartheta_{ch}}{cp+sn\hbar\omega\cos\vartheta_{ch}}. \qquad (24)$$

From Eq. (24) it follows that at the inelastic diffraction there is an asymmetry in the angular distribution of the scattered particle: $|\vartheta_{-s}|>\vartheta_s$, i.e., the main diffraction maximums are situated at different angles with respect to the direction of particle initial motion. However, in accordance with the condition $|s|\,n\hbar\omega/c<<p$ of the eikonal approximation this asymmetry is negligibly small and for the scattering angles of the main diffraction maximums from Eq. (24) we have $\vartheta_{-s}\simeq-\vartheta_s$. Hence, the main diffraction maximums will be situated at the angles

$$\vartheta_{\pm\overline{s}}=\pm\overline{s}\frac{n\hbar\omega}{cp}\sin\vartheta_{ch} \qquad (25)$$

with respect to the direction of the particle initial motion.

Note that in 1977 the formula Eq. (22) has been applied by the author for explanation of the experiment on energetic widening of an electron beam at the induced Cherenkov process in a gaseous medium [19], implemented in SLAC by R. Pantell and his group [20] (see, also the cited next experiment of this group in 1981, made in the same conditions).

These results, in particular, inelastic Kapitza–Dirac effect and diffraction on a traveling wave in a dielectric medium, as was mentioned above, had been received forty years ago and included in the monographs [21] and [23], as well as in the book [22]. Nevertheless, after the four decades, in 2015 by the same title has been published a paper in *New Journal of Physics, v. 17, 082002, 2015* by the authors Armen G Hayrapetyan, Karen K Grigoryan, Jörg B Götte and Rubik G Petrosyan [6], who report in the Abstract on the possibility of electrons diffraction scattering on a travelling EM wave in a dielectric medium: "We report on the possibility of diffracting electrons from light waves travelling inside a dielectric medium. We show that, in the frame of reference which moves with the group velocity of light, the travelling wave acts as a stationary diffraction grating from which electrons can diffract, similar to the conventional Kapitza–Dirac effect" (citation from the Abstract). Here only the difference with the known results is in the physical characteristic "group velocity of light" which is a rough mistake repeated also in the text, even for a monochromatic wave. As it has been shown above, diffraction effect is thoroughly the result of the phase relations and is conditioned exceptionally by the phase velocity of light that must be smaller than $c$. Beside this incorrectness, authors of this paper [6] ignored the existence of critical field in this process and influence of considered phenomenon of a particle "reflection" or capture on the diffraction effect, meanwhile one of these authors is also a co-author of both inelastic diffraction effect [9] and "reflection" phenomenon in the undulators [15]. Concerning the citation of considering papers devoted to diffraction effect on a travelling wave, these mechanically are included in the list of References of the paper [6] in irrelevant context by footnote: "see, for example...".

Concerning the method of calculation of the probability of multiphoton diffraction scattering, it is well known that there are two adequate methods - quantum mechanical and Helmholtz–Kirchhoff diffraction theory. The second method has been proposed and applied by F. Ehlotzky and C. Leubner in 1974 just for the calculation of the multiphoton diffraction probability of "Kapitza–Dirac effect" in strong laser fields [17]. Following to this calculation method, authors of the paper [6] obtain the known formula for the probability of multiphoton diffraction scattering in a dielectric medium Eq. (22) and claim on the possibility of diffraction effect in a dielectric medium.

Thus, the probability of $s$-photon diffraction in the paper [6] is given by the formula 16:

$$\mathcal{I}_s = \mathcal{I}_i J_s^2\left(\Delta\right);\ \Delta = \frac{eA_0 d}{\hbar c}. \tag{26}$$

The analogous expression for $s$-photon diffraction in the paper [8] is given by the formula 8 (which is the obtained above Eq. (22)):

$$W_s = J_s^2\left(\frac{ec^2 E_0 tP\sin\vartheta_{ch}}{\hbar\omega\mathcal{E}}\right) = J_s^2\left(\frac{eE_0 d}{\hbar\omega}\right), \tag{27}$$

where $d \equiv t\mathrm{v}\sin\vartheta_{ch}$ is the electron-wave interaction length.

Expressing the amplitude of the wave electric field strength $E_0$ by the amplitude $A_0$ of the wave vector potential ($E_0 = A_0\omega/c$), Eq. (27) will have a form:

$$W_s = J_s^2\left(\Delta\right);\ \Delta = \frac{eA_0 d}{\hbar c}. \tag{28}$$

i.e., the formula (26) is the same as formula (27) or (28) except of undetermined normalization constant $\mathcal{I}_i$, which should be $\mathcal{I}_i = 1$ in accordance to the total probability norm of the process, and general formula for the Bessel functions:

$$\sum_{s=-\infty}^{\infty} J_s^2\left(\Delta\right) = 1. \tag{29}$$

($s < 0$ -corresponds to photon radiation, $s > 0$ -to photon absorption in the wave field).

Note that considered effect of electrons inelastic diffraction takes place at the fulfilment of classical resonance condition Eq. (6). The latter is valid if the quantum recoil of an electron because of photons absorption-radiation processes can be neglected. Mathematically the quantum recoil is connected with the second order derivatives of the wave function which are neglected in the eikonal approximation (see Eq. (15)). For the diffraction effect with sufficiently long interaction time and large energy-momentum exchange one should take into account quantum recoil. At that, instead of the classical Cherenkov condition Eq. (6) we will have the quantum Cherenkov condition with the quantum recoil [21]:

$$1 - n\frac{\mathrm{v}}{c}\cos\vartheta = \frac{s\hbar\omega(n^2-1)}{2\mathcal{E}}. \tag{30}$$

The condition (30) has transparent physical interpretation in the intrinsic frame of reference of the slowed wave. In this frame, due to the conservation of particle energy and transverse momentum the real transitions in this - strongly quantum regime- occur from a $p'_x$ state to the $-p'_x$ one and we reach the Bragg diffraction effect on a slowed traveling wave in a dielectric medium at the fulfilment of the condition:

$$2p'_x = s\hbar k' \qquad (s = \pm 1, \pm 2...). \tag{31}$$

The latter expresses the condition of exact resonance between the particle de Broglie wave and the "wave motionless lattice". In particular, in this case when the above mentioned particle capture regime by the slowed traveling wave [10] takes place, we have the quantum effect of zone structure of particle states like the particle states in a crystal lattice, and the diffraction maxima takes place at the condition Eq. (30). For the more details acquaintance with the different regimes of electrons diffraction on a slowed traveling wave in a dielectric medium we refer the reader to the works [29–33].


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